

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application No.: 10/780,030 Confirmation No.: 9259
First Named Inventor: Park, Jongmin Filing Date: 17 February 2004
Group Art Unit: 2827 Examiner: Lam, David
Atty. Docket No.: R-0004 US
Title: Voltage Discharge Technique for Controlling Threshold-voltage
Characteristics of Floating-gate Transistor in Circuitry Such as Flash
EPROM
Assignee(s): ProMOS Technologies Inc.

Mountain View, California
26 April 2005

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PRELIMINARY AMENDMENT TO TEXT

Sir:

Please amend the above patent application in the following manner.

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